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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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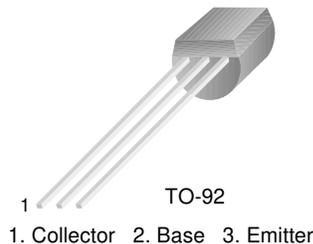
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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

BC237/238/239

Switching and Amplifier Applications

- Low Noise: BC239



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units	
V_{CES}	Collector-Emitter Voltage	: BC237	50	V
		: BC238/239	30	V
V_{CEO}	Collector-Emitter Voltage	: BC237	45	V
		: BC238/239	25	V
V_{EBO}	Emitter-Base Voltage	: BC237	6	V
		: BC238/239	5	V
I_C	Collector Current (DC)	100	mA	
P_C	Collector Power Dissipation	500	mW	
T_J	Junction Temperature	150	$^\circ\text{C}$	
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$	

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=2\text{mA}, I_B=0$: BC237	45		V
			: BC238/239	25		V
BV_{EBO}	Emitter Base Breakdown Voltage	$I_E=1\mu\text{A}, I_C=0$: BC237	6		V
			: BC238/239	5		V
I_{CES}	Collector Cut-off Current	$V_{CE}=50\text{V}, V_{BE}=0$ $V_{CE}=30\text{V}, V_{BE}=0$: BC237	0.2	15	nA
			: BC238/239	0.2	15	nA
h_{FE}	DC Current Gain	$V_{CE}=5\text{V}, I_C=2\text{mA}$	120		800	
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage	$I_C=10\text{mA}, I_B=0.5\text{mA}$ $I_C=100\text{mA}, I_B=5\text{mA}$		0.07	0.2	V
				0.2	0.6	V
$V_{BE}(\text{sat})$	Collector-Base Saturation Voltage	$I_C=10\text{mA}, I_B=0.5\text{mA}$ $I_C=100\text{mA}, I_B=5\text{mA}$		0.73	0.83	V
				0.87	1.05	V
$V_{BE}(\text{on})$	Base-Emitter On Voltage	$V_{CE}=5\text{V}, I_C=2\text{mA}$	0.55	0.62	0.7	V
f_T	Current Gain Bandwidth Product	$V_{CE}=3\text{V}, I_C=0.5\text{mA}, f=100\text{MHz}$ $V_{CE}=5\text{V}, I_C=10\text{mA}, f=100\text{MHz}$		85		MHz
				150	250	MHz
C_{ob}	Output Capacitance	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$		3.5	6	pF
C_{ib}	Input Base Capacitance	$V_{EB}=0.5\text{V}, I_C=0, f=1\text{MHz}$		8		pF
NF	Noise Figure	$V_{CE}=5\text{V}, I_C=0.2\text{mA},$ $f=1\text{KHz}, R_G=2\text{K}\Omega$ $V_{CE}=5\text{V}, I_C=0.2\text{mA}$ $R_G=2\text{K}\Omega, f=30\sim 15\text{KHz}$: BC237/238	2	10	dB
			: BC239		4	dB
			: BC239		4	dB

h_{FE} Classification

Classification	A	B	C
h_{FE}	120 ~ 220	180 ~ 460	380 ~ 800

Typical Characteristics

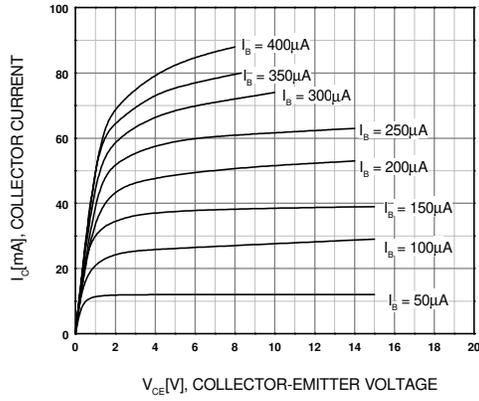


Figure 1. Static Characteristic

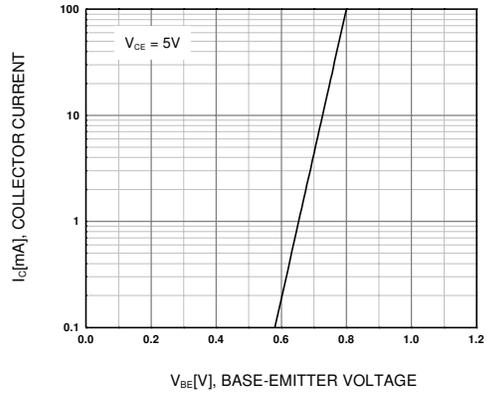


Figure 2. Transfer Characteristic

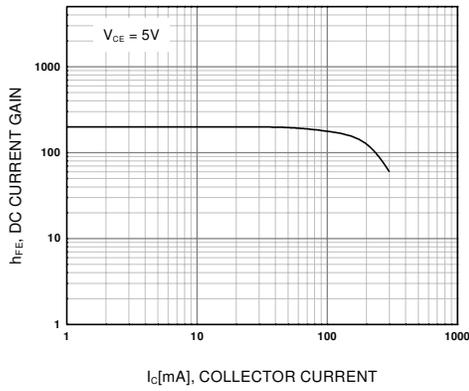


Figure 3. DC current Gain

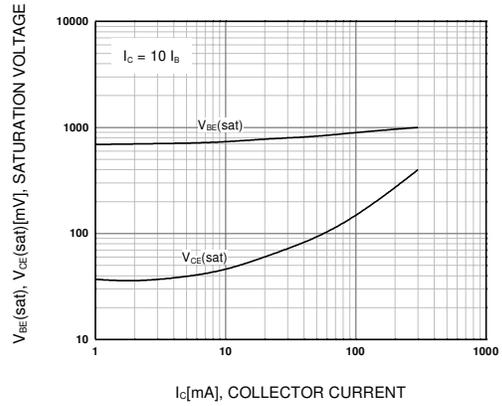


Figure 4. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

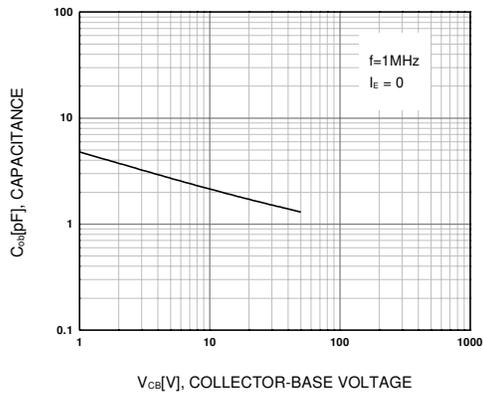


Figure 5. Output Capacitance

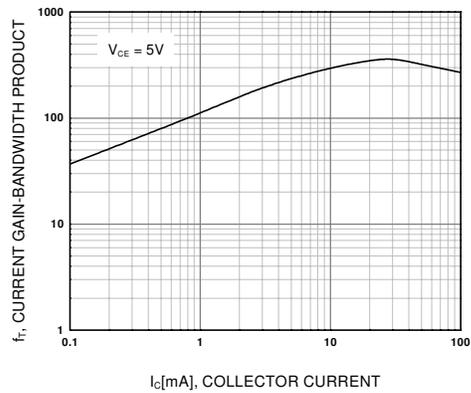
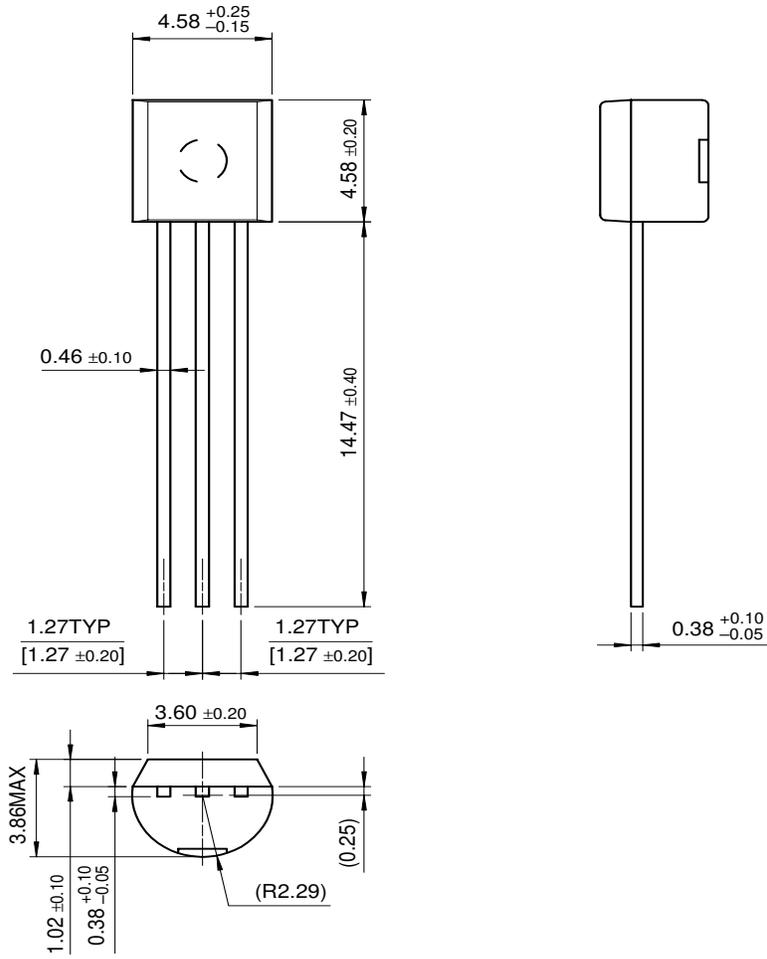


Figure 6. Current Gain Bandwidth Product

Package Dimensions

BC237/238/239

TO-92



Dimensions in Millimeters

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CoolFET™	FAST _r ™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOL™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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Definition of Terms

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